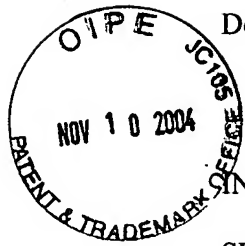


Docket No.: 250051US2S DIV/fcr



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

SIN RE APPLICATION OF: Mitsuhiro NOGUCHI, et al.

SERIAL NUMBER: 10/796,180

GROUP: 2824

FILED: March 10, 2004

EXAMINER: NGUYEN, Tuan T.

FOR: DATA WRITING METHOD FOR SEMICONDUCTOR MEMORY DEVICE AND
SEMICONDUCTOR MEMORY DEVICE

REQUEST TO CORRECT ALLOWED CLAIMS

MAIL STOP ISSUE FEE
COMMISSIONER FOR PATENTS
P.O. BOX 1450
ALEXANDRIA, VA 22313-1450

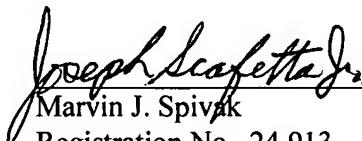
SIR:

In the matter of the above-identified application for patent, we hereby request
correction of your records to reflect the correct allowed claims.

The allowed claims should be: 1-6, 62-73.

Respectfully Submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.


Marvin J. Spivak

Registration No. 24,913

Joseph Scafetta, Jr.

Registration No. 26,803

Eckhard H. Kuesters

Registration No. 28,870

Customer Number

22850

Tel. (703) 413-3000
Fax. (703) 413-2220
(OSMMN 05/04)